

Spectrum Devices Corporation

Semiconductor Engineering and Manufacturing

RF & MICROWAVE TRANSISTORS HF APPLICATIONS

FEATURES:

- 30 MHz
- 28 Volts
- $P_{OUT} = 25W$ min, with 18 dB Gain
- Efficiency 35%
- Common Emitter
- Class A/AB Operation
- Improved Collector-Base Breakdown Voltage: 110 Volts Min.
- Replacement for MRF426



HF28-25

0.380" DIAMETER SOE PACKAGE

DESCRIPTION:

The HF28-25 is an epitaxial silicon NPN planar transistor designed primarily for Class A/AB RF amplifiers operating in the 2-30 MHz band. This device utilizes ballasted emitter resistors and improved metallization systems to achieve optimum load mismatch capability. The HF28-series products utilize the unique Spectrum Devices' Bipolar process which offers a 70% improvement in collector-base breakdown voltage, enhancing reliability while maintaining RF performance

<u>ABSOLUTE MAXIMUM RATINGS</u>: (T_{CASE} = 25°C)

Symbol	Parameter	Value	Unit
Vсво	Collector to Base Voltage	110	V
VCEO	Collector to Emitter Voltage	35	V
Vево	Emitter to Base Voltage	4.0	V
IC (max)	Continuous Collector Current	5.0	Α
Po	Total Dissipation at 25°C Stud	60	W
TJ	Junction Temperature	+200	°C
Tstg	Storage Temperature	-65 to +150	°C

THERMAL DATA:

RTH(J-C) Thermal Resistance Junction-case	2.9	°C/W
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<u>ELECTRICAL SPECIFICATIONS</u> ($T_{CASE} = 25^{\circ}C$)

DC CHARACTERISTICS

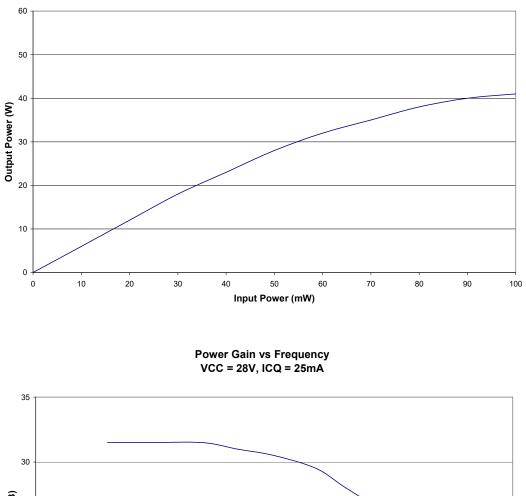
Symbol	Test Conditions		Value			TT •/
			Min.	Тур.	Max.	Unit
ВУсво	Ic = 200 mA	$I_E = 0 mA$	110			V
BVCES	Ic = 200 mA	$V_{BE} = 0 V$	110			V
BVCEO	Ic = 200 mA	$I_B = 0 mA$	35			V
BVEBO	$I_E = 10 \text{ mA}$	$I_C = 0 mA$	4.0			V
Ісво	$V_{CB} = 30 V$	$I_E = 0 mA$			1	mA
hfe	$V_{CE} = 5 V$	$I_C = 500 mA$	15		200	

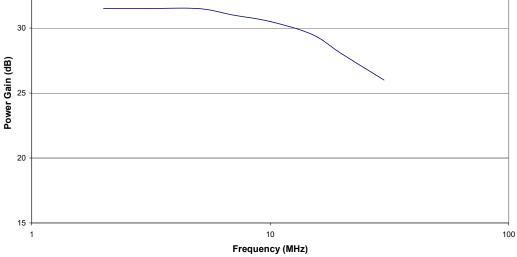
RF CHARACTERISTICS

~				Valu			
Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
Роит	f = 30 MHz	$V_{CC} = 28 V$	Icq=25 mA	25			W
Gp	f = 30 MHz	$V_{CC} = 28 V$	Icq=25 mA	18			dB
nc	f = 30 MHz	$V_{CC} = 28 V$	Icq=25 mA	35			%
Сов	f = 30 MHz	$V_{CC} = 28 V$	Icq=25 mA		65		pF

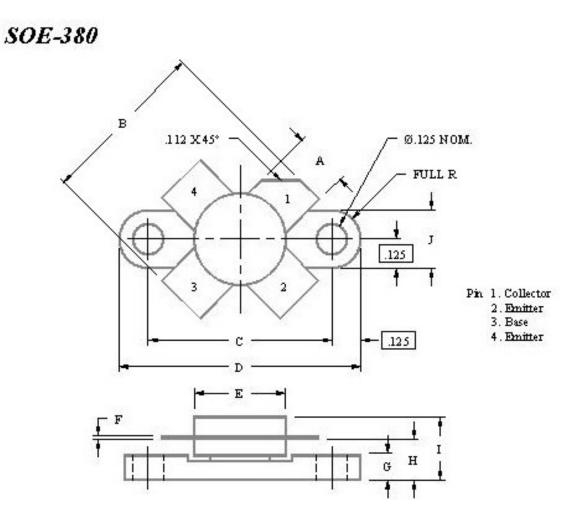
TYPICAL DATA

Output Power vs Input Power f = 30MHz, V_{CC} = 28V, I_{CQ} = 25mA





PACKAGE MECHANICAL DATA



	Minimum Inches/MM	Maximum Inches/MM		Minimum Inches/MM	Maximum Inches/MM	
А	.220/5.59	.230/5.84	G	.085/2.16	.105/2.67	
В	.785/19.94		Н	.160/4.06	.180/4.57	
С	.720/18.29	.730/18.54	Ι	.260/7.11		
D	.970/24.64	.980/24.89	J	.240/6.10	.255/6.48	
E	.385/9.78					
F	.004/0.10	.006/0.15				

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